	<h2 style="color: red;">FQB25N33TM_F085</h2>
	<p>Hersteller-Teilenummer: FQB25N33TM_F085</p> <hr/> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: FQB25N33TM_F085 Fairchild/ON Semiconductor</p> <hr/> <p>Datenblätter:  FQB25N33TM_F085.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 32363 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
 <p style="font-size: small;">Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB25N33TM_F085
Hersteller	Fairchild/ON Semiconductor
Beschreibung	FQB25N33TM_F085 Fairchild/ON Semiconductor
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	32363 pcs Stock
Serie	Automotive, AEC-Q101
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.1W (Ta), 250W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	330V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	25A (Tc)
Rds On (Max) @ Id, Vgs	230 mOhm @ 12.5A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	75nC @ 15V
Eingabekapazität (Ciss) (Max) @ Vds	2010pF @ 25V
Verpackung	Tape & Reel (TR)


















































FQB25N33TM_F085 ist neu im Original, Suche FQB25N33TM_F085 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB25N33TM_F085 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB25N33TM_F085: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB27N25TM FAIRCH FQB27N25TM FAIRCH</p>	 <p>FQB27N25 FAIRCHI FQB27N25 FAIRCHI</p>	 <p>FQB25N33TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 330V 25A D2PAK</p>	 <p>FQB27N25TM_AM002 Fairchild/ON Semiconductor MOSFET N-CH 250V 25.5A D2PAK</p>
 <p>FQB25N33 FAIRCHI FQB25N33 FAIRCHI</p>	 <p>FQB27N25TM-F085 AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 25.5A 131M</p>	 <p>FQB25N33TM Fairchild/ON Semiconductor MOSFET N-CH 330V 25A D2PAK</p>	 <p>FQB24N08TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 80V 24A D2PAK</p>

heiße Teile

Mehr

 FQB19N10TM	 FQB19N10TM	 FQB19N20	 FQB19N20C	 FQB19N20CTM
 FQB19N20CTM	 FQB19N20L	 FQB19N20LTM	 FQB19N20LTM	 FQB19N20TM
 FQB19N20TM	 FQB1N60TM	 FQB1N60TM	 FQB20N06L	 FQB20N60FTM
 FQB20N60TM	 FQB22P10	 FQB22P10TM	 FQB22P10TM	 FQB22P10TM_F085
 FQB24N08TM	 FQB24N08TM	 FQB25N33	 FQB25N33TM	 FQB25N33TM
 FQB27N25TM	 FQB27P06	 FQB27P06TM	 FQB27P06TM	 FQB2N50C
 FQB2N60TM	 FQB2N60TM	 FQB2N80TM	 FQB2N80TM	 FQB2NA90TM
 FQB2NA90TM	 FQB2P25TM	 FQB2P25TM	 FQB30N06	 FQB30N06L
 FQB30N06LTM	 FQB30N06LTM	 FQB30N06TM	 FQB30N06TM	 FQB32N12V2
 FQB32N12V2TM	 FQB32N12V2TM	 FQB32N20	 FQB32N20C	 FQB32N20CTM

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited